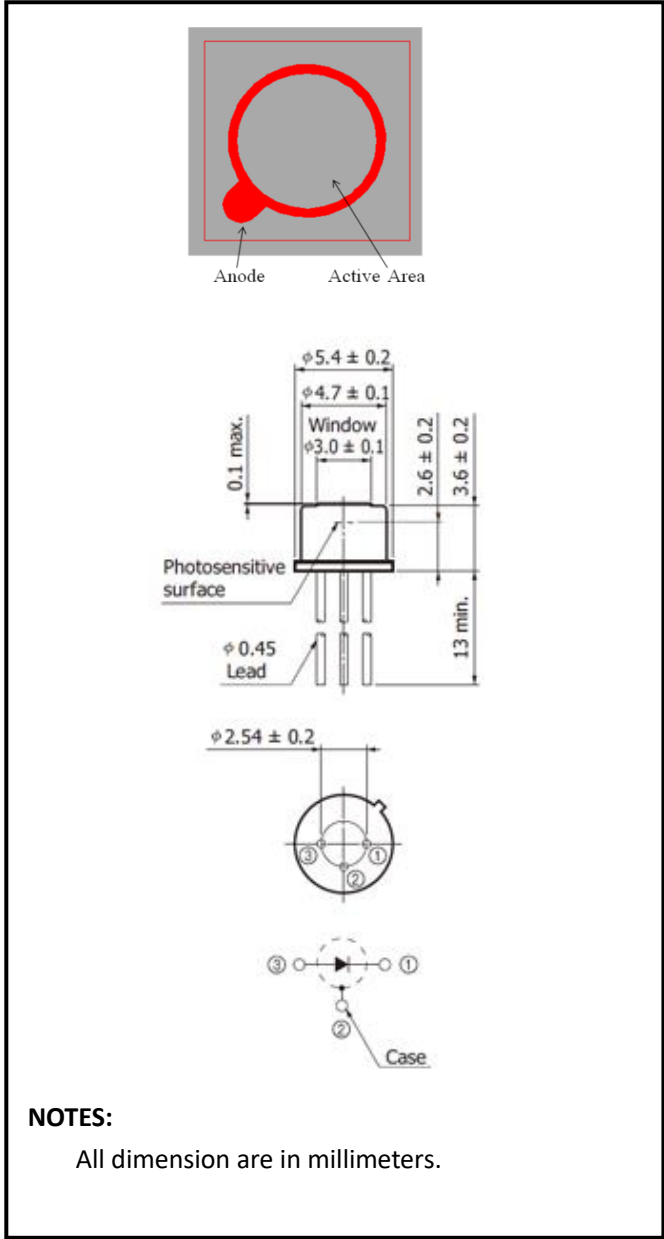


InGaAs PIN Photodiode

IGA210



Description

OTRON SENSOR IGA210 is a type of active area size of 0.21mm diameter active area IR sensitive detectors which exhibit excellent responsivity from 1000nm to 1680nm, allowing high sensitivity to weak signals.

These large active area devices are ideal for use in infrared instrumentation and monitoring applications.

We can also custom type according to customer chip size or Package style enquiry.

Features

- * Low voltage operation
- * Large Active Area Diameter
- * Spectral Range 800nm to 1700nm

General Ratings

- * Type InGaAs Photodiode
- * High linearity
- * Chip active area: $\phi 210\mu\text{m}$
- * Low dark current

Applications

- * Optical Instrumentation
- * NIR Sensing
- * Laser Power Measurement
- * Power meters

Information in this technical datasheet is believed to be correct and reliable. However, no responsibility is assumed for possible inaccuracies or omission. Specifications are subject change without notice

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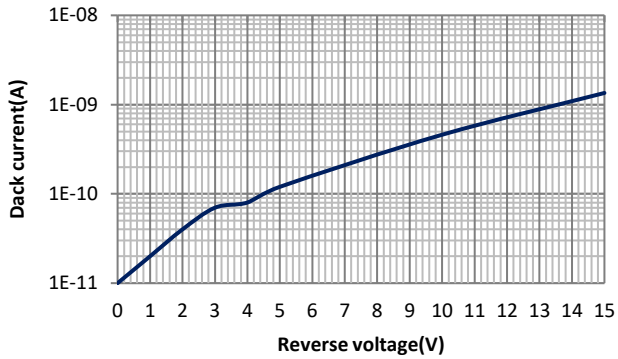


Absolute Maximum Ratings (Ta=25°C)

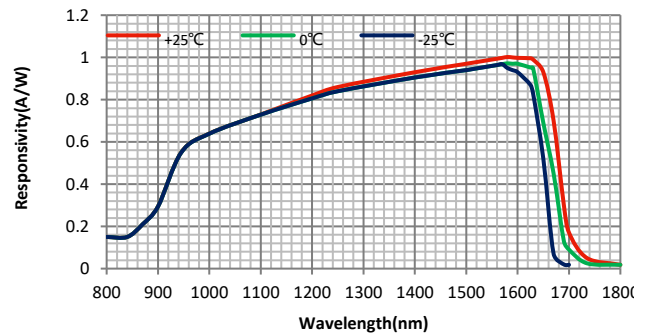
Parameter	Symbol	Condition	Min.	Typ.	Max.	Unit
Chip size	S	360×360×155				um
Active area	A	φ 210				um
Forward current	I _F	10				mA
Reverse current	I _R	10				mA
Dark current	I _D	V _R =0V		10		pA
		V _R =5V		120		
-3dBm bandwidth	BW	R _L =50Ω,	0.5			GHz
Forward Voltage	V _F	I _F =1mA			0.7	V
Reverse breakdown voltage	V _{(BR)R}	I _R =10μA Ev=0lx			30	V
Junction Capacitance	C _J	V _R =0V f=1MHz		6.29		pF
		V _R =5V f=1MHz		4		
Photo sensitivity	S _R	1310nm	0.90	0.95		A/W
		1550nm	0.95	1.10		
Spectral Application Range	λ _{range}		1000		1680	nm
Spectral Response-Peak	λ _p			1600		nm
Shunt resistance	R _{sh}	V _R =10mV		1		GΩ
Saturation power	L	V _R =0V;λ=1.55μm	6			dBm
Angular Resp 50% Resp Pt	θ _{1/2}			±55		
Noise Equivalent Power	NEP	V _R =5V λ=1550nm		6.53×10 ⁻¹³		W/Hz ^{1/2}
Specific Detectivity	D*	V _R =5V λ=1550nm		5.69×10 ¹⁰		cm(Hz/W) ^{1/2}

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■ Dark current vs. reverse voltage

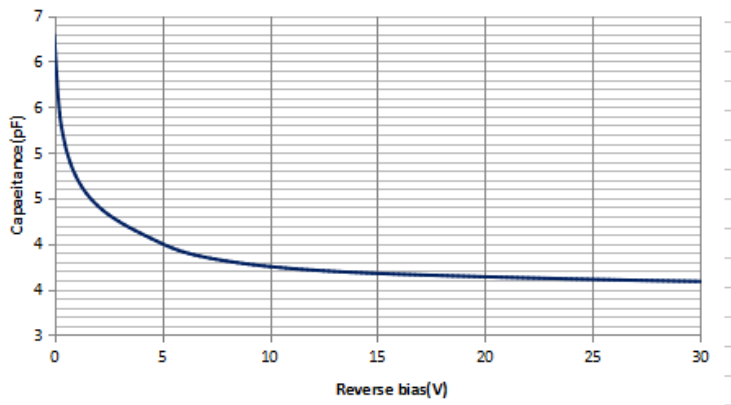


■ Spectral response



■ Relative Junction Capacitance

VS. Voltage



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